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PAMELA D. SQUYRES
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):	
Christopher J. Petti et al.	Group Art Unit: Unknown
Application No.:	Examiner: Unassigned
Filed: December 3, 2003	
Title: Semiconductor Device Including Junction Diode Contacting Contact-Antifuse Unit Comprising Silicide	
Attorney Docket No.: MA-109	

INFORMATION DISCLOSURE STATEMENT

Assistant Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir or Madam,

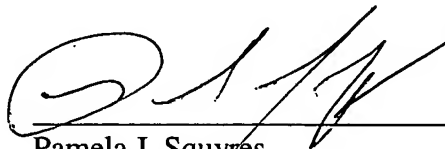
Pursuant to the obligation under 37 CFR § 1.56 and in conformance with 37 CFR §§ 1.97-1.99, Applicants hereby submit documents A1-A14 listed on the attached form PTO-1449 for consideration by the Examiner. Copies of non-patent

documents are enclosed herewith. Applicants request that the Examiner review the entire disclosure of these documents and make them of record.

The filing of this Information Disclosure Statement does not constitute an admission that the information cited herein is, or is considered to be, material to patentability as defined in 37 CFR §1.56(b). Further Applicants reserve the right to contest that any of the information submitted herewith is prior art against the present application.

Dated: December 3, 2003

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'P. J. Squyres', is written over a horizontal line.

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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Complete if Known

Application Number Unknown

Filing Date December 3, 2003

First Name and Inventor Petti, Christopher

Group Art Unit Unknown

Examiner Name Unknown

Sheet 1 of 1

Attorney Docket No: MA-109

US PATENT DOCUMENTS

Examiner Initial *	Cite No	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
	A1	10/185507		Vyvoda et al.			06/27/2002
	A2	10/326470		Herner et al.			12/19/2002
	A3	10/440882		Vyvoda			05/19/2003
	A4	10/610804		Herner et al.			06/30/2003
	A5	6,034,882	03/07/2000	Johnson et al.			
	A6	6,420,215	07/16/2002	Knall et al.			
	A7	6,525,953	02/25/2003	Johnson			
	A8	6,541,312	04/01/2003	Vyvoda et al.			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T ²
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OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	A9	CHIANG, STEVE., et al. , "Antifuse Structure Comparison for Field Programmable Gate Arrays", IEDM 92-611, (4/1992),24.6.1-24.6.4	
	A10	HAMDY, ESMAT., et al. , "Dielectric Based Antifuse for Logic and Memory ICs", IEDM 88, (1988),786-789	
	A11	HERNER, S..B. , et al. , "Polycrystalline silicon/CoSi2 Schottky diode with integrated SiO2 antifuse: a nonvolatile memory cell", Applied Physics Letters, Volume 82, Number 23, 9 June 2003, (6/9/2003),4163-4165	
	A12	KONAKOVA, R..V. , et al. , "Ohmic Contacts for Microwave Diodes", Proc. 22nd International Conference on Microelectronics (MIEL 2000), VOL 2, NIS, Serbia, 14-17 May 2000, (1/1999),477-480	
	A13	SHIH, CHIH-CHING., et al. , "Characterization and Modeling of a Highly Reliable Metal-to-Metal Antifuse for High-Performance and High-Density Field-Programmable Gate Arrays", 1997 IEEE, (9/1997),25-33	
	A14	WANG, SHOU-EN., et al. , "High-Performance Metal/Silicide Antifuse", IEEE Electron Device Letters, VOL.13, NO 9, September 1992, (9/1992),471-472	

EXAMINER**DATE CONSIDERED**

Substitute Disclosure Statement Form (PTO-1449)

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional) 2 Applicant is to place a check mark here if English language Translation is attached